

Absolute maximum ratings

($T_a=25^\circ\text{C}$)

Symbol	Ratings	Unit
V_{CB0}	120	V
V_{CE0}	120	V
V_{EB0}	6	V
I_c	4	A
I_{CP}	6 (PW \leq 1ms, Du \leq 50%)	A
I_B	0.5	A
I_F	4 (PW \leq 0.5ms, Du \leq 25%)	A
I_{FSM}	6 (PW \leq 10ms, Single)	A
V_R	120	V
P_T	5 ($T_a=25^\circ\text{C}$) 25 ($T_c=25^\circ\text{C}$)	W
V_{ISO}	1000 (Between fin and lead pin, AC)	V _{rms}
T_j	150	$^\circ\text{C}$
T_{stg}	-40 to +150	$^\circ\text{C}$
θ_{j-c}	5	$^\circ\text{C}/\text{W}$

Electrical characteristics

($T_a=25^\circ\text{C}$)

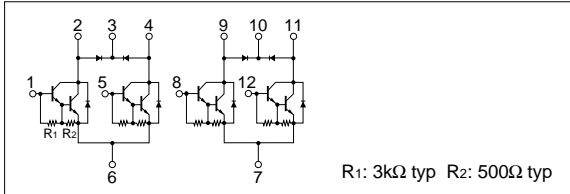
Symbol	Specification			Unit	Conditions
	min	typ	max		
I_{CB0}			10	μA	$V_{CB}=120\text{V}$
I_{EB0}			10	mA	$V_{EB}=6\text{V}$
V_{CE0}	120			V	$I_c=25\text{mA}$
h_{FE}	2000	5000	15000		$V_{CE}=2\text{V}, I_c=2\text{A}$
$V_{CE}(\text{sat})$		1.0	1.5	V	$I_c=2\text{A}, I_B=2\text{mA}$
$V_{BE}(\text{sat})$		1.6	2.0	V	
t_{on}		0.6		μs	$V_{CC}=40\text{V},$ $I_c=2\text{A},$ $I_{B1}=-I_{B2}=10\text{mA}$
t_{stg}		5.0		μs	
t_f		2.0		μs	

Diode for flyback voltage absorption

($T_a=25^\circ\text{C}$)

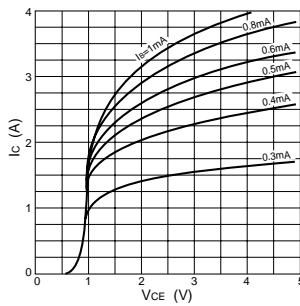
Symbol	Specification			Unit	Conditions
	min	typ	max		
V_R	120			V	$I_R=10\mu\text{A}$
V_F			1.2	V	$I_F=1\text{A}$
I_R			10	μA	$V_R=120\text{V}$
t_{rr}		100		ns	$I_F=\pm 100\text{mA}$

Equivalent circuit diagram

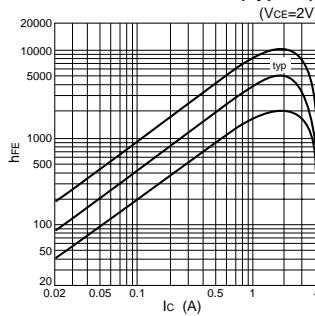


Characteristic curves

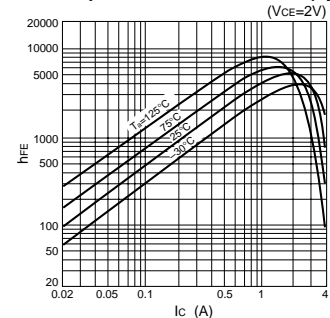
I_c - V_{CE} Characteristics (Typical)



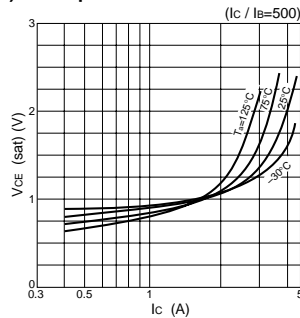
h_{FE} - I_c Characteristics (Typical)



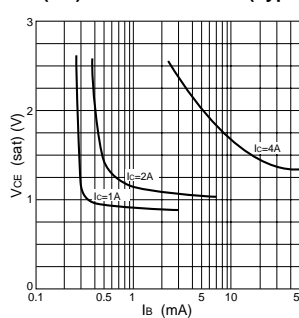
h_{FE} - I_c Temperature Characteristics (Typical)



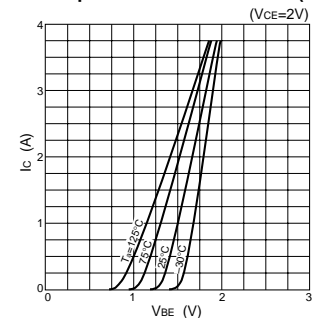
$V_{CE}(\text{sat})$ - I_c Temperature Characteristics (Typical)



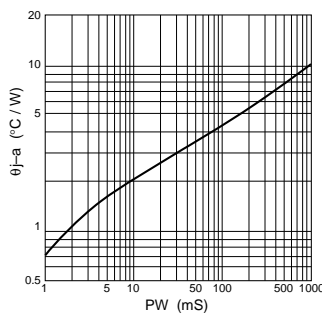
$V_{CE}(\text{sat})$ - I_B Characteristics (Typical)



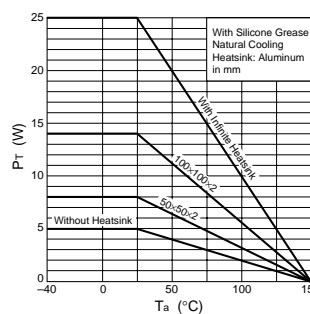
I_c - V_{BE} Temperature Characteristics (Typical)



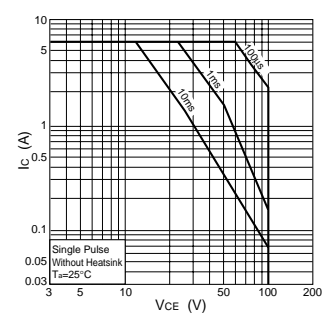
θ_{j-a} -PW Characteristics



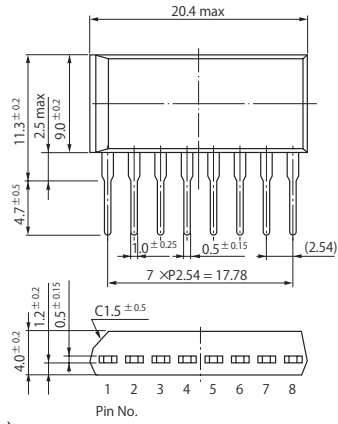
P_T - T_a Characteristics



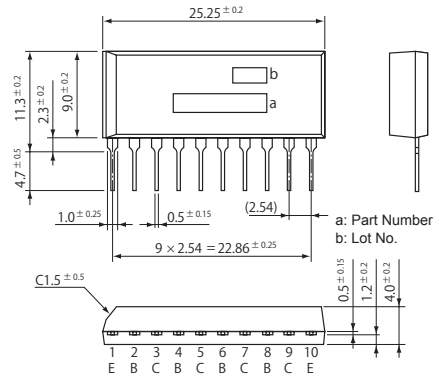
Safe Operating Area (SOA)



• SIP 8 (STA8Pin)



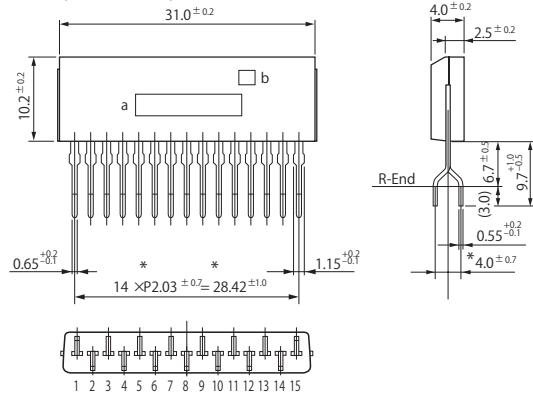
• SIP 10 (STA10Pin)



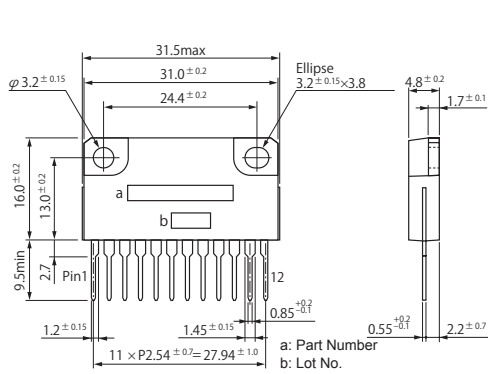
• SIP 12 (SMA12Pin)



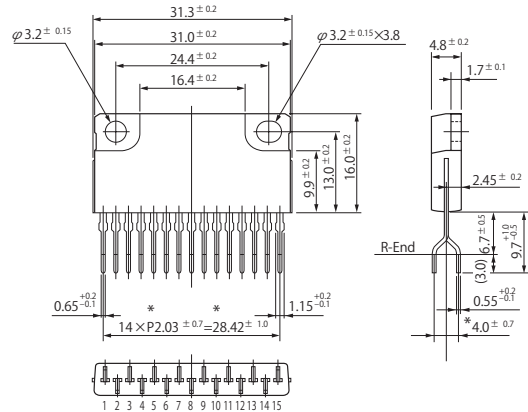
• SIP 15 (SMA15Pin)



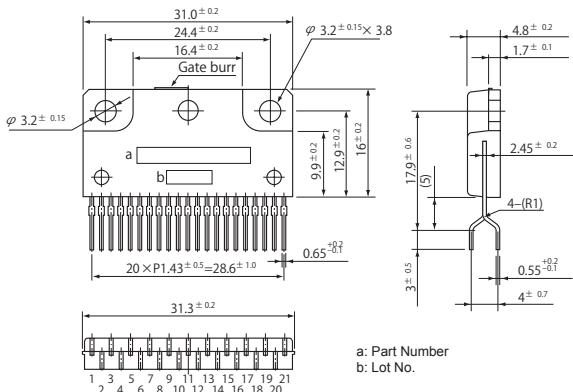
• SIP 12 with Fin (SLA12Pin)



• SIP 15 with Fin (SLA15Pin)



• SIP 21 with Fin (SLA21Pin)



(Unit:mm)

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - Pre-Biased](#) category:

Click to view products by [Sanken](#) manufacturer:

Other Similar products are found below :

[MMUN2217LT1G](#) [FP101-TL-E](#) [RN1607\(TE85L,F\)](#) [DRC9A14E0L](#) [DTA124GKAT146](#) [DTA144WETL](#) [DTA144WKAT146](#)

[DTC113EET1G](#) [DTC115TETL](#) [DTC115TKAT146](#) [DTC124TETL](#) [DTC144ECA-TP](#) [DTC144VUAT106](#) [MUN5241T1G](#)

[BCR158WH6327XTSA1](#) [NSBA114TDP6T5G](#) [NSBA143TF3T5G](#) [NSBA143ZF3T5G](#) [NSBC114EF3T5G](#) [NSBC114YF3T5G](#)

[NSBC123TF3T5G](#) [NSBC143TF3T5G](#) [NSVMUN2212T1G](#) [NSVMUN5111DW1T3G](#) [NSVMUN5314DW1T3G](#) [NSVUMC2NT1G](#)

[SMMUN2134LT1G](#) [SMUN2212T1G](#) [SMUN5235T1G](#) [SMUN5330DW1T1G](#) [SSVMUN5312DW1T2G](#) [2SC3650-TD-E](#) [RN1303\(TE85L,F\)](#)

[RN4605\(TE85L,F\)](#) [BCR135SH6327XT](#) [TTEPROTOTYPE79](#) [UMC3NTR](#) [DTA113EET1G](#) [EMA2T2R](#) [EMH15T2R](#) [SDTA114YET1G](#)

[SMMUN2111LT3G](#) [SMMUN2113LT1G](#) [SMMUN2114LT1G](#) [SMMUN2211LT3G](#) [SMUN2214T3G](#) [SMUN5113DW1T1G](#)

[SMUN5335DW1T1G](#) [NSBA114YF3T5G](#) [NSBC114TF3T5G](#)